



JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

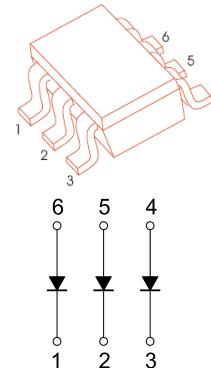
SOT-363 Plastic-Encapsulate Diodes

RB731XN SCHOTTKY BARRIER DIODE**FEATURES**

- Small Power Mold Type
- Low V_F
- High Reliability

APPLICATIONS

- General Rectification

MARKING: 731**SOT-363****MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)**

Symbol	Parameter	Value	Unit
V_R	DC Blocking Voltage	40	V
I_o	Average Rectified Forward Current	30	mA
I_{FSM}	Non-repetitive Peak Forward Surge Current@10ms	200	mA
P_D	Power Dissipation	200	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	500	$^\circ\text{C}/\text{W}$
T_j	Junction Temperature	125	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~+150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=100\mu\text{A}$	40			V
Reverse current	I_R	$V_R=10\text{V}$			1	μA
Forward voltage	V_F	$I_F=1\text{mA}$			0.37	V
Total capacitance	C_{tot}	$V_R=1\text{V}, f=1\text{MHz}$			2	pF